

● FEATURES

- 0.30 inch (7.62 mm) Digit Height.
- Low current operation.
- SMD type.
- Gray face, White segment.
- RoHS compliant, Pb Free.

● DESCRIPTION

The YSD-3010SA-D-GW are 0.30 inch (7.62 mm) height
Dual digit 7-segment displays.

This device utilizes Super Bright Amber LED chip which are made from AlGaInP on a
Transparent GaAs, substrate.

The display has Gray face, White segment.

● DEVICE

PART NO	DESCRIPTION
YSD-3010SA-D-GW	Common Anode

RoHS Compliance



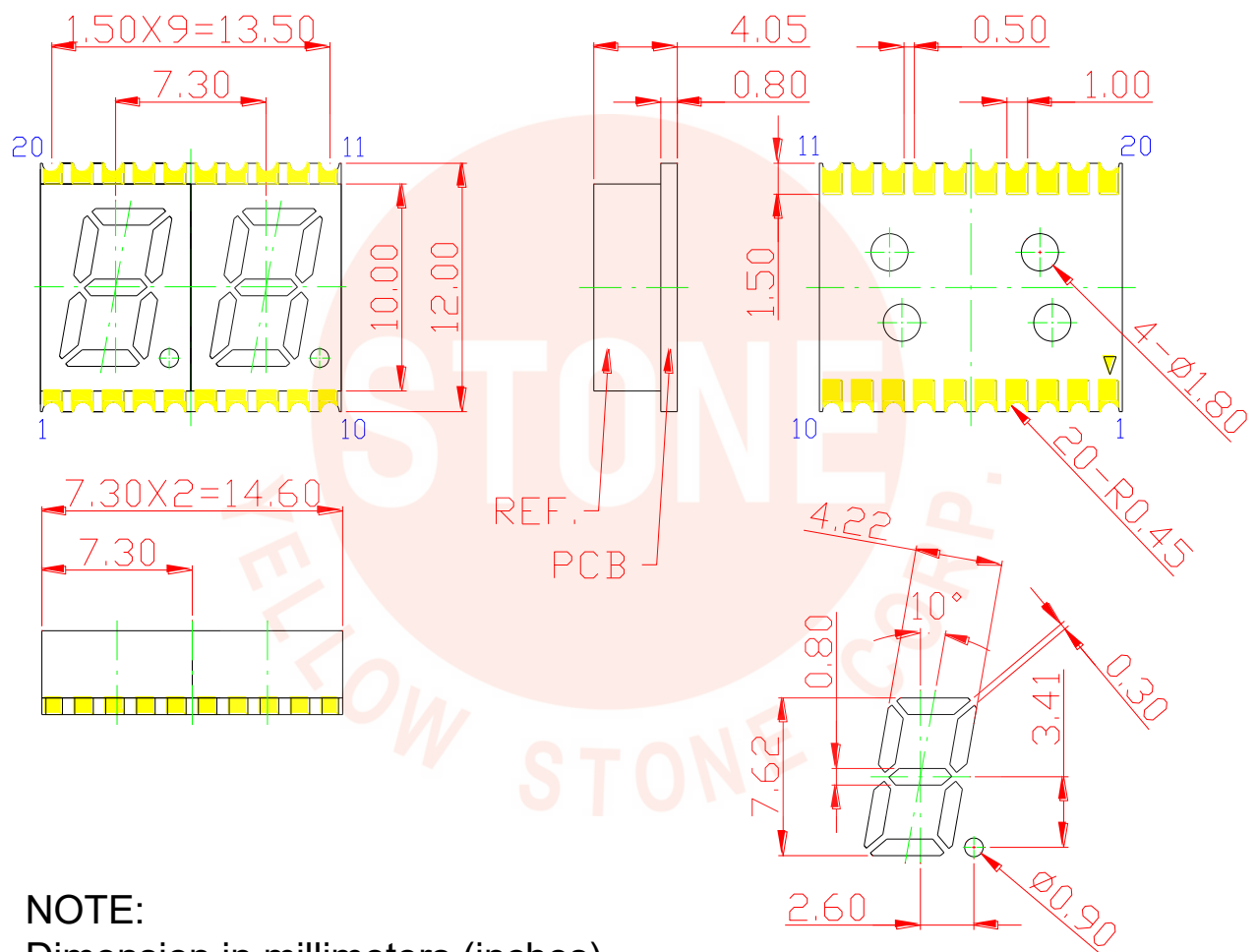
Pb free.





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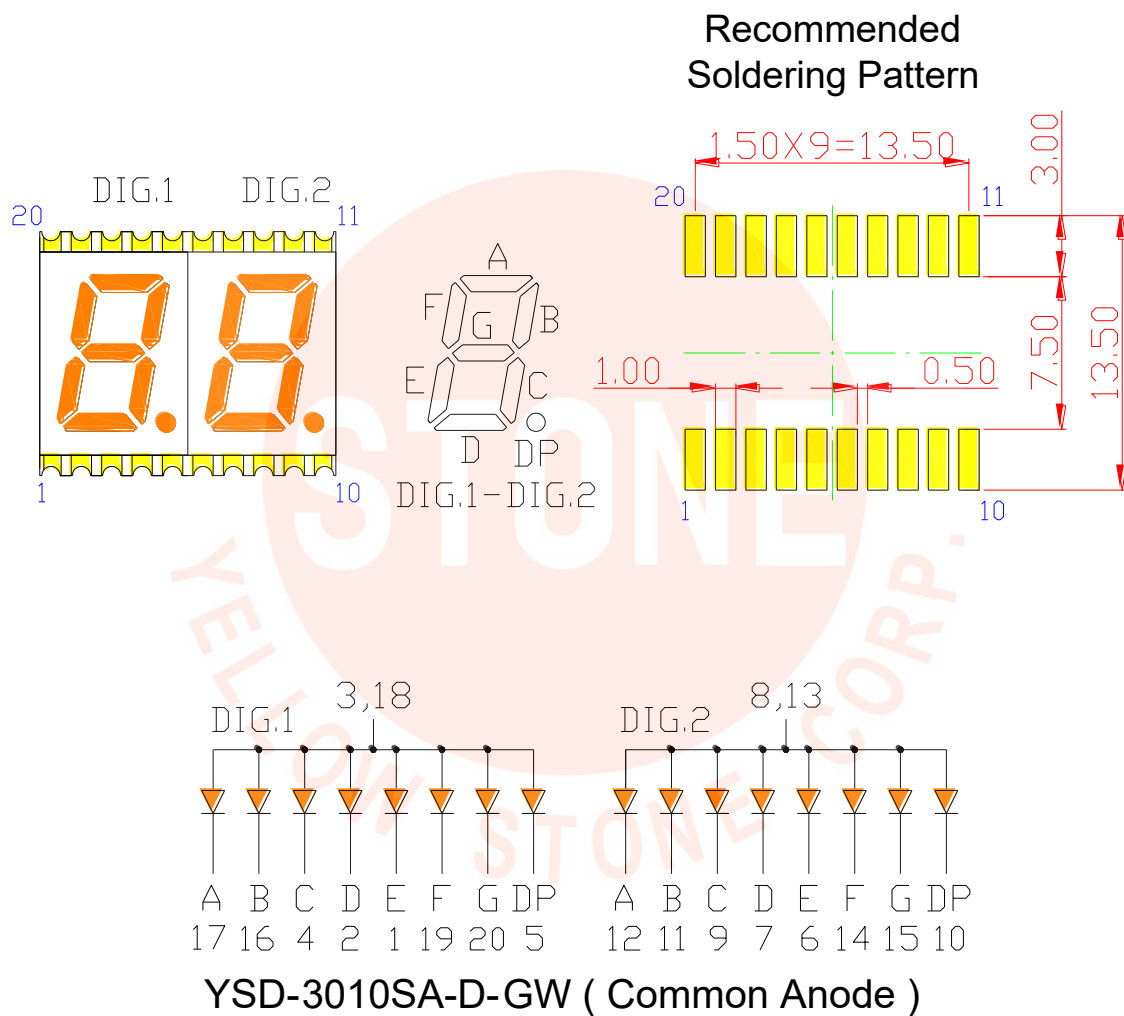
● MECHANICAL DIMENSIONS



NOTE:

Dimension in millimeters (inches),
And tolerances are $\pm 0.25\text{mm}$ (.01") specified.

● TYPICAL INTERNAL EQUIVALENT CIRCUIT



● SA: SUPER BRIGHT AMBER (AlGaInP/GaAs)

ABSOLUTE MAXIMUM RATING AT Ta=25°C

Parameter	Symbol	Maximum Rating	Unit
Power dissipation	P _{AD}	70	mW
Derating liner from 25°C	-	0.28	mA / °C
Continuous forward current	I _{AF}	25	mA
Peak current (duty cycle 1/10, 1kHz)	I _{PF}	90	mA
Reverse voltage	V _R	5	V
Operating temperature	T _{OPR}	-40 to +105	°C
Storage temperature	T _{STG}	-40 to +105	°C

ELECTRICAL - OPTICAL CHARACTERISTICS AT Ta=25°C

Characteristic	Symbol	Condition	Min.	Type.	Max.	Unit
Forward Voltage, (Per Dice)	V _F	I _F =20mA	-	2.0	2.4	V
Reverse Current, (Per Dice)	I _R	V _R =5V	-	-	10	μA
Peak Wavelength	λ _P	I _F =20mA	-	612	-	nm
Dominant Wavelength	λ _D	I _F =20mA	601	-	611	nm
Luminous Intensity	I _V	I _F =10mA	8	-	30	mcd
Spectral radiation bandwidth	Δλ	I _F =20mA	-	20	-	nm



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● SA: BIN GRADE (Unit : mcd) 10mA

Super Bright Amber	H	I	J
	8.0 – 15.0	15.1 – 22.0	22.1 - 30.0

● SA: HUE GRADE (λ_D : nm)

1	2	3
601.0 – 604.0	604.1 – 608.0	608.1 – 611.0

● AVAILABLE BIN / HUE TABLE

H1	H2	H3
I1	I2	I3
J1	J2	J3

● SA: SUPER BRIGHT AMBER (AlGaInP/GaAs) CURVE

Typical Electro-optical Characteristic Curves
(25 °C Free Air Temperature Unless Otherwise Specified)

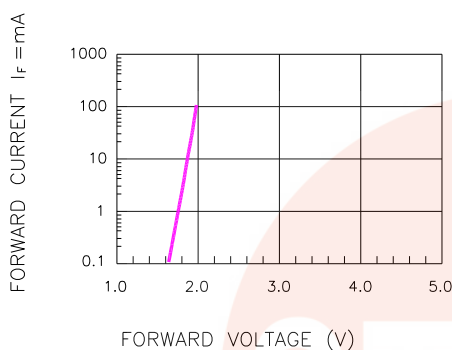


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

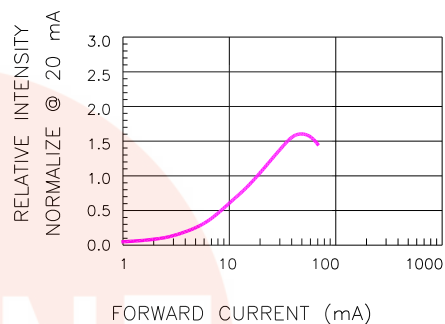


Fig.2 RELATIVE INTENSITY VS. FORWARD CURRENT

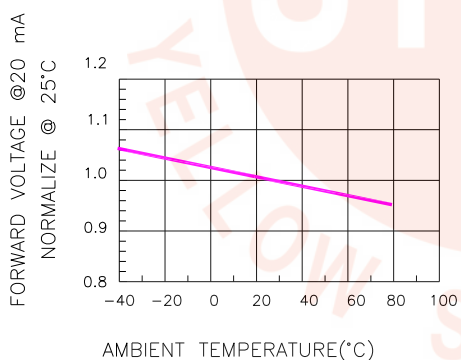


Fig.3 FORWARD VOLTAGE VS. TEMPERATURE

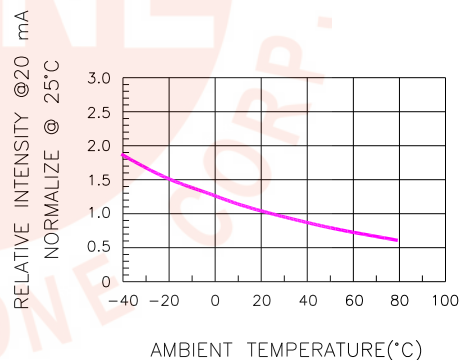


Fig.4 RELATIVE INTENSITY VS. TEMPERATURE

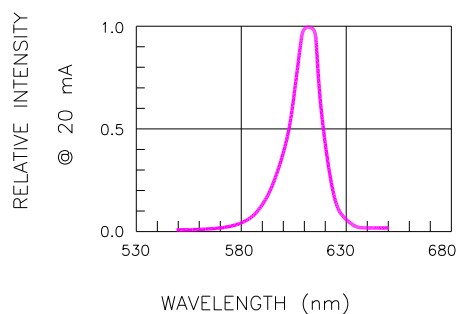


Fig.5 RELATIVE INTENSITY VS. WAVELENGTH

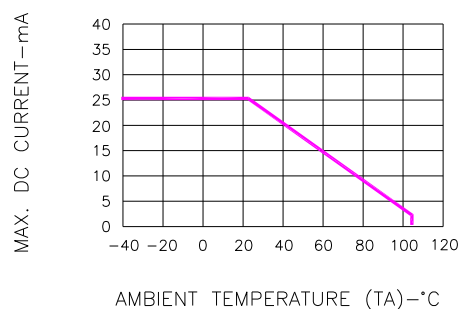
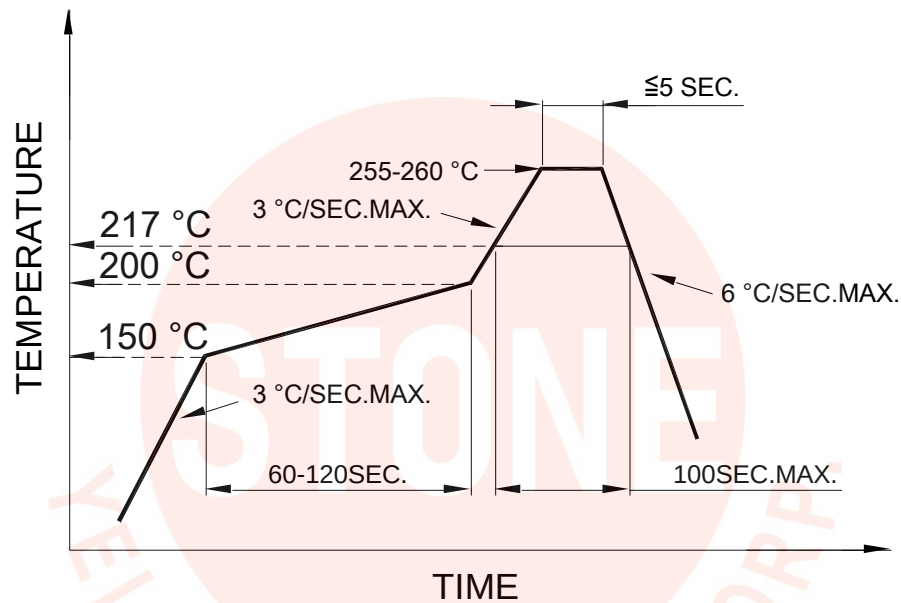


Fig.6 MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE

● SMT REFLOW SOLDERING INSTRUCTIONS

SMT Soldering Profile

Pb free reflow soldering Profile



- We recommend the reflow temperature 245°C (+/- 5°C).
The maximum soldering temperature should be limited to 260°C.
- Number of reflow process shall be 2 times or less.

● SOLDERING IRON

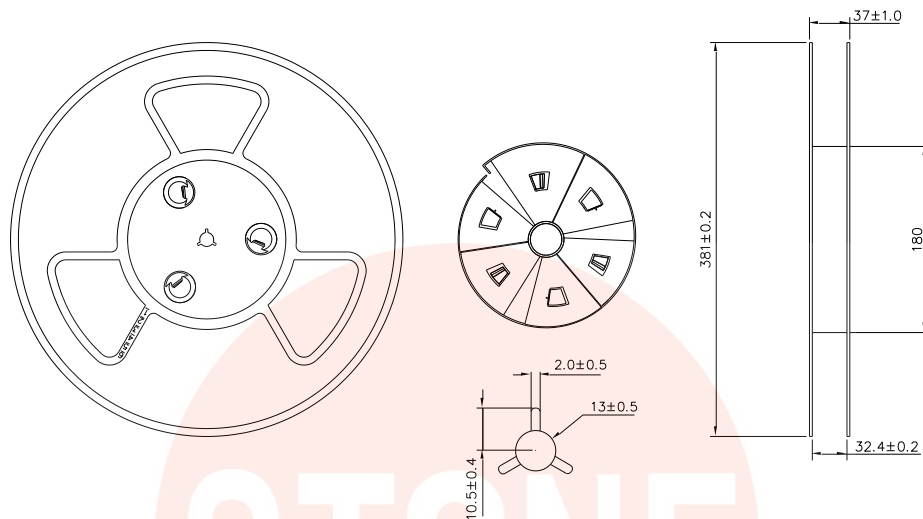
Basic spec is ≤ 4 sec when 260°C. If temperature is higher, time should be shorter (+10°C → 1 sec). Power dissipation of Iron should be smaller Than 15W, and temperature should be controllable. Surface temperature Of the device should be under 230°C.

● REWORK

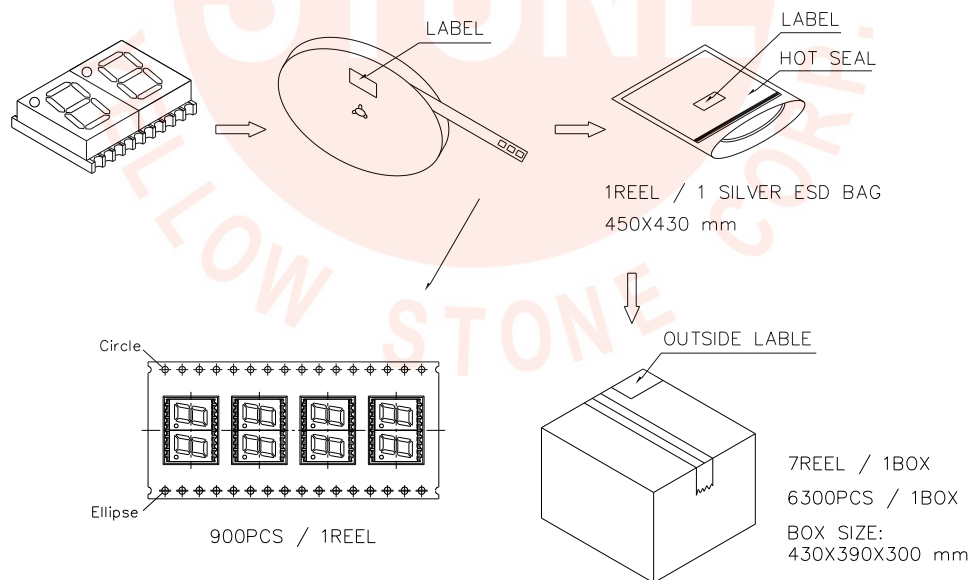
- Customer must finish rework within 3 sec. under 350°C.
- The head of soldering iron cannot touch copper foil.



● REEL DIMENSIONS



● PACKING & LABEL SPECIFICATIONS



● STORAGE CONDITION

In factory original sealed bag package

TEMPERATURE CONDITION	HUMIDITY CONDITION
5°C ~ 30°C	Below 60%RH

After opened and not in factory original sealed bag package

TEMPERATURE CONDITION	HUMIDITY CONDITION	STORAGE TIME
5°C ~ 30°C	Below 60%RH	Within 4 weeks (MSL as level 2a)